

Notice of References Cited	Application/Control No.	Applicant(s)/Patent Under
	10/580,683	Reexamination KOBAYASHI, RYUJI
	Examiner Xinning(Tom) Niu	Art Unit 2828
		Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
	B	US-			
	C	US-			
	D	US-			
	E	US-			
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FOREIGN PATENT DOCUMENTS

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	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	S. L. Chuang. Physics of Optoelectronic Devices. New York: John Wile & Sons, 1995.
*	V	Y. Sakata et al. "All-Selective MOVPE-Grown 1.3-um Strained Multi-quantum-Well Buried-Heterostructure Laser Diodes," IEEE Journal of Quantum Electronics, Vol. 35, No. 3, March 1999
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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